

# LOW DROP POWER SCHOTTKY RECTIFIER

### MAIN PRODUCTS CHARACTERISTICS

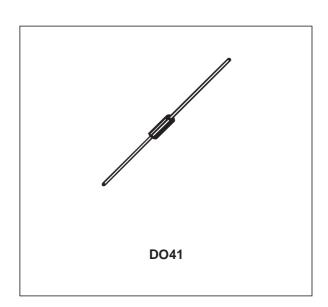
I <sub>F(AV)</sub>	1 A
V <sub>RRM</sub>	40 V
Tj	150°C
V <sub>F</sub> (max)	0.45 V

### **FEATURES AND BENEFITS**

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- LOW FORWARD VOLTAGE DROP
- AVALANCHE CAPABILITY SPECIFIED



Axial Power Schottky rectifier suited for Switch Mode Power Supplies and high frequency DC to DC converters. Packaged in DO41 these devices are intended for use in low voltage, high frequency inverters, free wheeling, polarity protection and small battery chargers.



# **ABSOLUTE RATINGS** (limiting values)

Cumbal	Symbol Parameter -		Value			Unit
Symbol			1N5817	1N5818	1N5819	Oilit
V <sub>RRM</sub>	Repetitive peak reverse voltage			30	40	V
I <sub>F(RMS)</sub>	RMS forward current			10		
I <sub>F(AV)</sub>	Average forward current	$T_L = 125^{\circ}C$ $\delta = 0.5$	1			А
I <sub>FSM</sub>	Surge non repetitive forward current	tp = 10 ms Sinusoidal	25			А
P <sub>ARM</sub>	Repetitive peak avalanche power	tp = 1µs Tj = 25°C	1200	1200	900	W
T <sub>stg</sub>	Storage temperature range			- 65 to + 150		
Tj	Maximum operating junction temperature *			150		
dV/dt	Critical rate of rise of reverse voltage			10000		

\* : 
$$\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$$
 thermal runaway condition for a diode on its own heatsink

July 2003 - Ed: 4A

## THERMAL RESISTANCES

Symbol	Paramete	Value	Unit	
R <sub>th (j-a)</sub>	Junction to ambient	Lead length = 10 mm	100	°C/W
R <sub>th (j-l)</sub>	Junction to lead	Lead length = 10 mm	45	°C/W

### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests Conditions		1N5817	1N5818	1N5819	Unit
I <sub>R</sub> *	Reverse leakage	Tj = 25°C	$V_R = V_{RRM}$	0.5	0.5	0.5	mA
	current	Tj = 100°C		10	10	10	mA
V <sub>F</sub> *	Forward voltage drop	Tj = 25°C	I <sub>F</sub> = 1 A	0.45	0.50	0.55	V
		Tj = 25°C	I <sub>F</sub> = 3 A	0.75	0.80	0.85	V

Pulse test : \* tp = 380  $\mu$ s,  $\delta$  < 2%

To evaluate the conduction losses use the following equations :

 $P = 0.3 \text{ x } I_{F(AV)} + 0.090 I_{F_{(RMS)}}^{2} \text{ for 1N5817 / 1N5818}$   $P = 0.3 \text{ x } I_{F(AV)} + 0.150 I_{F_{(RMS)}}^{2} \text{ for 1N5819}$ 

Fig. 1: Average forward power dissipation versus average forward current (1N5817/1N5818).

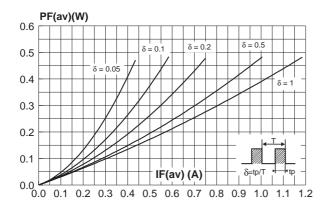


Fig. 2-1: Average forward current versus ambient temperature ( $\delta = 0.5$ ) (1N5817/1N5818).

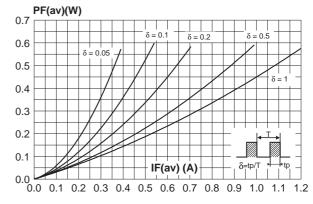
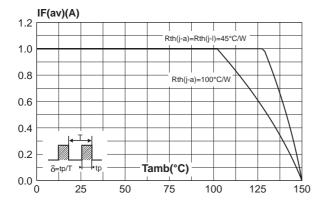
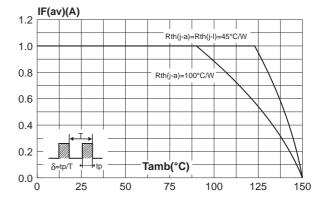


Fig. 2: Average forward power dissipation versus

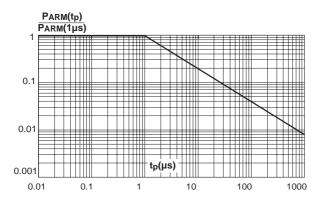
average forward current (1N5819).

Fig. 2-2: Average forward current versus ambient temperature ( $\delta$ =0.5) (1N5819).

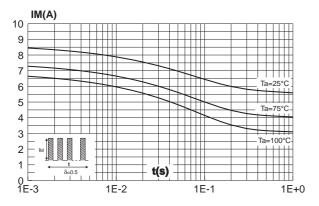




**Fig. 3:** Normalized avalanche power derating versus pulse duration.



**Fig. 5-1:** Non repetitive surge peak forward current versus overload duration (maximum values) (1N5817/1N5818).



**Fig. 6:** Relative variation of thermal impedance junction to ambient versus pulse duration (epoxy printed circuit board, e(Cu)=35mm, recommended pad layout).

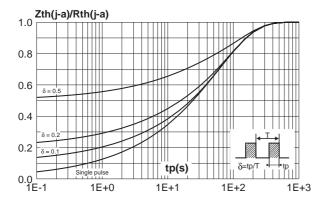
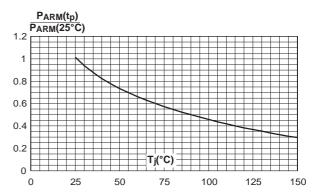
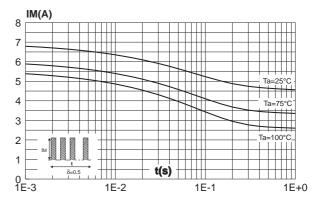


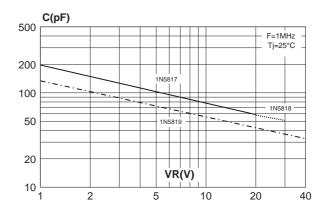
Fig. 4: Normalized avalanche power derating versus junction temperature.



**Fig. 5-2:** Non repetitive surge peak forward current versus overload duration (maximum values) (1N5819).

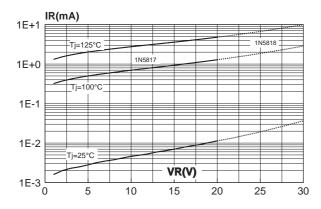


**Fig. 7:** Junction capacitance versus reverse voltage applied (typical values).

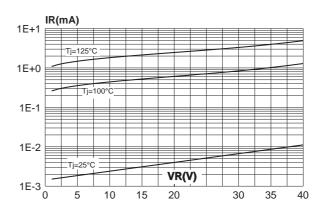


57

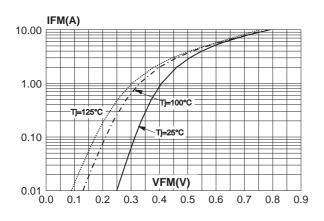
Fig. 8-1: Reverse leakage current versus reverse voltage applied (typical values) (1N5817/1N5818).



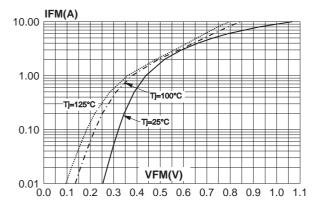
**Fig. 8-2:** Reverse leakage current versus reverse voltage applied (typical values) (1N5819).



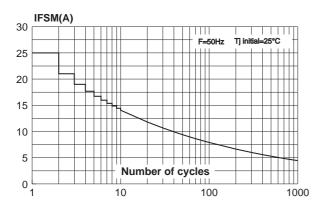
**Fig. 9-1:** Forward voltage drop versus forward current (typical values) (1N5817/1N5818).



**Fig. 9-2:** Forward voltage drop versus forward current (typical values) (1N5819).



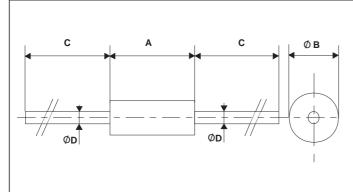
**Fig. 10:** Non repetitive surge peak forward current versus number of cycles.



4/5

## **PACKAGE MECHANICAL DATA**

DO41 plastic



	DIMENSIONS				
REF.	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
А	4.1	5.2	0.16	0.205	
В	2	2.7	0.08	0.107	
С	25.4		1		
D	0.71	0.86	0.028	0.034	

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
1N581x	Part number cathode ring	DO41	0.34g	2000	Ammopack
1N581xRL	Part number cathode ring	DO41	0.34g	5000	Tape & reel

Epoxy meets UL94,V0

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